

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)
Shunpei YAMAZAKI et al.) Group Art Unit: 2822
Serial No. 09/837,877)
Filed: April 19, 2001) Examiner: M. Lewis
For: SEMICONDUCTOR DEVICE)
)

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231, on December 2, 2002.

Adele M. Stamper

AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action mailed July 31, 2002, please amend the above identified application as follows.

IN THE ABSTRACT

Please replace the current abstract with the attached abstract on a separate sheet. A marked version of the changes to the abstract is also included.

IN THE SPECIFICATION:

Please replace paragraph [0084] with the following

-- [0084] Through this step, a source region 319, a drain region 320, an LDD regions 321a and 321b, and a channel formation region 322 of the NTFT are defined. A drain region 323 and a source region 324 of the PTFT are also doped

NVA248178.1